

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	300	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	1064	mJ	
	Power Dissipation		429	W	
P _D	Derate Above 25°C		2.86	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
R _{0JC}	Thermal Resistance, Junction to Case		0.35	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, L = 0.3mH, $I_{AS} = 84A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

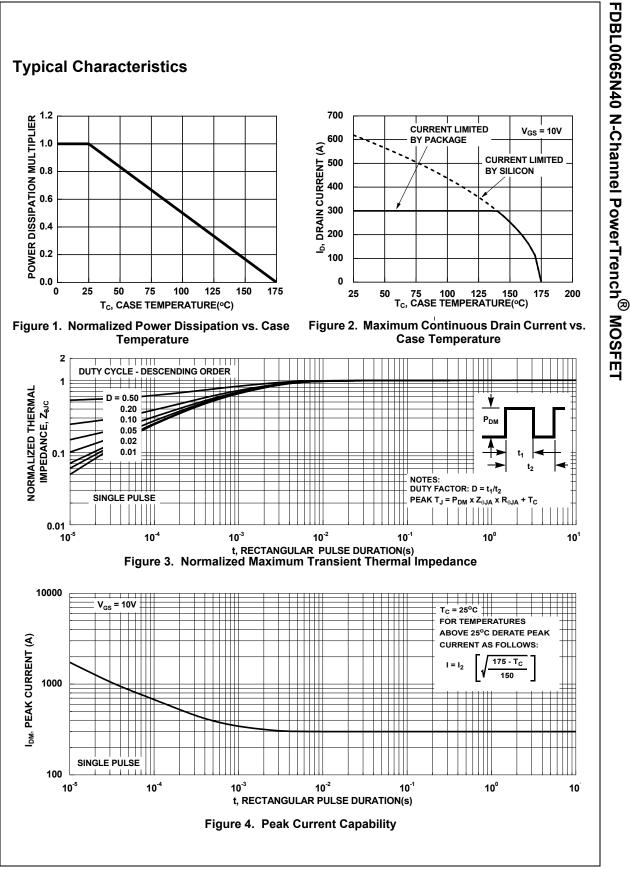
Package Marking and Ordering Information

Device Marking	Device	Package			
FDBL0065N40	FDBL0065N40	MO-299A	-	-	-

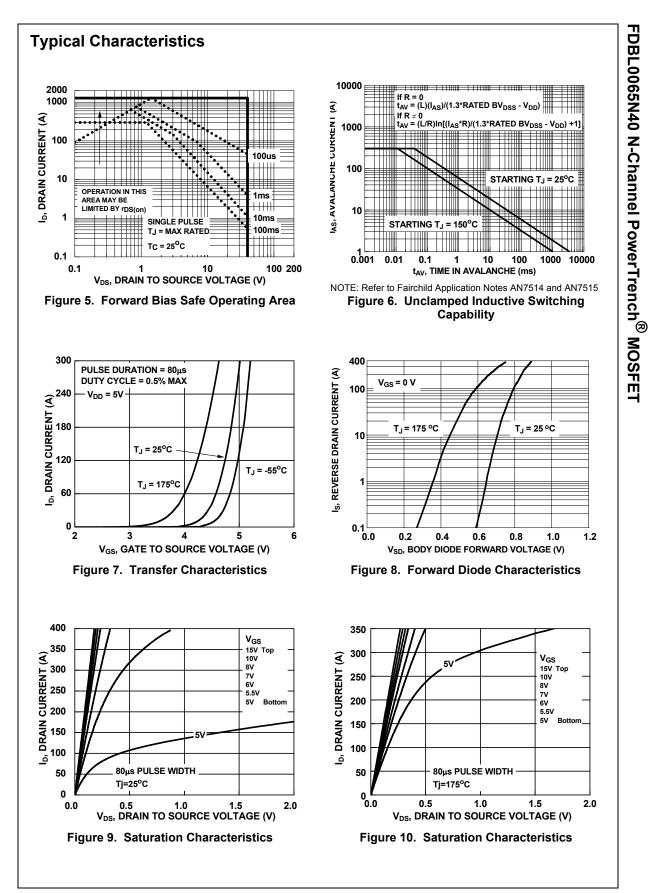
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Symbol	Parameter	Test C	onditions	Min.	Тур.	Max.	Units
	racteristics				,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	-	
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
		V _{DS} =40V, T		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	V _{GS} = 0V T	_J = 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D =$	= 250μA	2.0	3.0	4.0	V
D	Drain to Source On Resistance	D /	J = 25°C	-	0.50	0.65	mΩ
R _{DS(on)}		V _{GS} = 10V T	_J = 175 ^o C (Note 4)	-	0.86	1.10	mΩ
Dynami C _{iss}	c Characteristics				15900	-	рF
C _{oss}	Output Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	4025	-	p. pF
C _{rss}	Reverse Transfer Capacitance			-	604	-	pF
R _a	Gate Resistance			-	2.6	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	V _{DD} = 20V	-	220	296	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	$I_{\rm D} = 80A$	-	29	39	nC
Q _{gs}	Gate to Source Gate Charge			-	73	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	41	-	nC
Switchi	ng Characteristics				-	221	ns
t _{d(on)}	Turn-On Delay			-	54	-	ns
r	Rise Time	V _{DD} = 20V, I _D =	= 80A,	-	82	-	ns
t _{d(off)}	Turn-Off Delay	V _{GS} = 10V, R _G		-	106	-	ns
t _f	Fall Time			-	52	-	ns
t _{off}	Turn-Off Time			-	-	215	ns
Drain-S	ource Diode Characteristics						
V _{SD}	Source to Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
- 20	-	I _{SD} = 40A, V _{GS}		-	-	1.2	V
t _{rr}	Reverse Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s,$		-	119	133	ns
Q _{rr}	Reverse Recovery Charge		V _{DD} =32V		228	274	nC

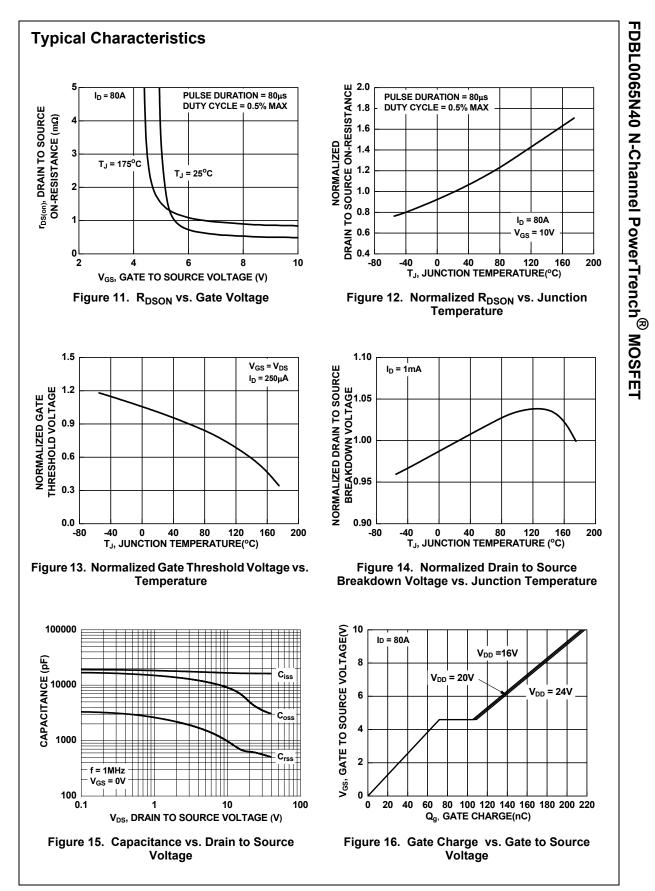
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



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FDBL0065N40 Rev.C3



FDBL0065N40 Rev.C3



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